NSN 5961-01-355-1925

Unitized Semiconductor Devices - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-355-1925 **Inclosure Material:** Ceramic or plastic **Overall Length:** Between 0.640 inches and 0.786 inches **Overall Height:** Between 0.225 inches and 0.360 inches **Overall Width:** Between 0.290 inches and 0.320 inches **Component Name And Quantity:** 4 transistor **Mounting Method:** Terminal **Semiconductor Material:** Silicon all transistor Voltage Rating In Volts Per Characteristic: 40.0 gate voltage, instantaneous all semiconductor **Current Rating Per Characteristic:** 2.00 amperes drain current all semiconductor **Power Rating Per Characteristic:** 1.75 watts total power dissipation all semiconductor **Maximum Operating Tempurature Per Measurement Point:** 150.0 degrees celsius junction **Terminal Type And Quantity:** 14 pin Shelf Life: N/a **Unit Of Measure:** Demilitarization: No

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